# Middle Power LED Series 3030

# LM302Z Plus CRI80

#### **Features & Benefits**

- 0.6 W class middle power LED
- EMC resin for high reliability
- Standard form factor for design flexibility (3.0 × 3.0 mm)







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#### 1. Characteristics

#### a) Absolute Maximum Rating

Item	Symbol	Rating	Unit	Condition
Operating Solder Temperature	Ta	-40 ~ +105	°C	-
Storage Temperature	T <sub>stg</sub>	-40 ~ +100	°C	-
LED Junction Temperature	Tj	125	°C	-
Forward Current	I <sub>F</sub>	200	mA	-
Pulse Forward Current	I <sub>Fp</sub>	300	mA	Duty 1/10, pulse width 10 ms
Assembly Process Temperature	-	260 <10	°C s	-
ESD (HBM)	-	5	kV	-

#### b) Electro-optical Characteristics ( $I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$ )

ltem	Nominal CCT (K)	Rank	Bin	Min.	Тур.	Max.	Unit
			BZ	5.8	-	6.0	
Forward Voltage (VF)		GB	B1	6.0	-	6.2	V
Torward voltage (VF)			B2	6.2		6.4	v
			В3	6.4	-	6.6	
Reverse Voltage (@ 5 mA)				0.7	-	1.2	V
Color Rendering Index (R <sub>a</sub> )		5		80	-	-	-
Thermal Resistance (junction to solder point)				-	12	-	°C/W
Beam Angle				-	120	-	o

#### Note:

Samsung maintains measurement tolerance of: forward voltage = ±0.1 V, luminous flux = ±5 %, CRI = ±3

#### 2. Product Code Information

1	2	3	4	5	6	7	8	9	10	11	12	13	14	15	16	17	18
S	Р	М	W	Н	3	3	2	6	F	Р	5	G	В	V	0	S	0

Digit	PKG Information	Code	Specification
123	Samsung Package Middle Power	SPM	
4 5	Color	WH	White
6	Product Version	3	Zener version
789	Form Factor	326	3.0 x 3.0 x 0.65 mm; 2 pads
10	Sorting Current	F	150 mA
11	Chromaticity Coordinates	Р	MacAdam
12	CRI	5	Min. 80
13 14	Forward Voltage (V)	GB	BZ 5.8~6.0 5.8~6.6 Bin B1 6.0~6.2 Code: B2 6.2~6.4 B3 6.4~6.6
15 16	CCT (K)	W☆ V☆ U☆ R☆ Q☆ P☆	2700    WN, WP, WQ, WR, WS, WT, WU      3000    VN, VP, VQ, VR, VS, VT, VU      3500    UN, UP, UQ, UR, US, UT, UU      4000    Bin Code    TN, TP, TQ, TR, TS, TT, TU      5000    RN, RP, RQ, RR, RS, RT, RU      5700    QN, QP, QQ, QR, QS, QT, QU      6500    PN, PP, PQ, PR, PS, PT, PU      ☆ : "0" (Whole Bin)    "3" (MacAdam 3- step)
17 18	Luminous Flux (lm)	S0	SF 124~133 lm Bin SG 133~142 lm Code: SH 142~151 lm

#### a) Luminous Flux Bins (I<sub>F</sub> = 150 mA, $T_s = 25$ °C)

Nominal CCT (K)	CRI Min.	Product Code	Flux Bin	Flux Range (Φ <sub>v</sub> , Im)
2700	80	SPMWH3326FP5GBW☆S0	SF	124 – 133
2700	00	SPIMWID3320FF3GBW ¥ SU	SG	133 – 142
3000	80	SPMWH3326FP5GBV☆S0 ·····	SF	124 – 133
3000	80	SHMMU3320FF3GBV ☆SU	SG	133 – 142
3500	80	SPMWH3326FP5GBU☆S0 ·····	SG	133 – 142
5500	00	3FWW03320FF3GDU × 30	SH	142 – 151
4000	80	SPMWH3326FP5GBT☆S0 ·····	SG	133 – 142
4000	00	3FWW03520FF3GD1 x 30	SH	142 – 151
5000	80	SPMWH3326FP5GBR☆S0	SG	133 – 142
5000	00	SPININU3320FP3GBR¥SU	SH	142 – 151
5700	80	SPMWH3326FP5GBQ☆S0	SG	133 – 142
5700	OU	37MMM13320LL30Pd/X20	SH	142 – 151
6500	80	SPMWH3326FP5GBP☆S0	SG	133 – 142
0000	00	5710100020F73GB7 X3U	SH	142 – 151

#### Note:

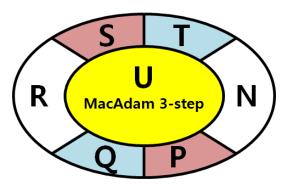
"☆" can be "0" (Whole Bin), "3" (MacAdam 3-step), "Y" (Kitting)

#### b) Kitting Rule

#### 1) Y Kitting bin Concept

- 1. Under agreement between customer and SAMSUNG ELECTRONICS, SAMSUNG can supply kitting bin ( Color).
- 2. A Chromaticity Coordinates of kitting bin is mixed by kitting procedure.(below kitting simulation)

#### [Kitting example]



#### [Binning Information]

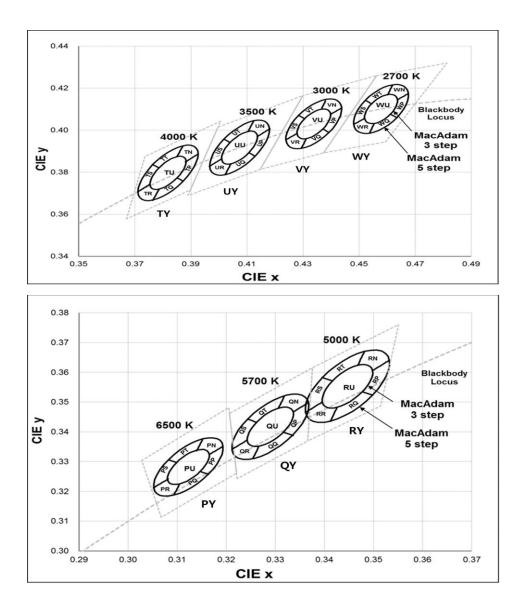
	Bin #1	Bin #2
	U	U
CIE	Ν	R
CIE	Р	S
	Q	Т
	SF	SF
	SF	SG
IV	SG	SG
	SG	SH
	SH	SH

#### c) Color Bins ( $I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$ )

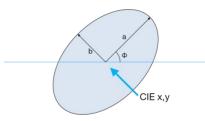
Nominal CCT (K)	CRI Min.	Product Code	Color Rank	Chromaticity Bins					
		SPMWH3326FP5GBW0S0	W0 (Whole Bin)	WN, WP, WQ, WR, WS, WT, WU					
2700	80	SPMWH3326FP5GBW3S0	W3 (MacAdam 3-step)	WU					
		SPMWH3326FP5GBWYS0	WY (Kitting)	WN, WP, WQ, WR, WS, WT, WU					
		SPMWH3326FP5GBV0S0	V0 (Whole Bin)	VN, VP, VQ, VR, VS, VT, VU					
3000	80	SPMWH3326FP5GBV3S0	V3 (MacAdam 3-step)	VU					
		SPMWH3326FP5GBVYS0	VY (Kitting)	VN, VP, VQ, VR, VS, VT, VU					
		SPMWH3326FP5GBU0S0	U0 (Whole Bin)	UN, UP, UQ, UR, US, UT, UU					
3500	80	SPMWH3326FP5GBU3S0	U3 (MacAdam 3-step)	UU					
							SPMWH3326FP5GBUYS0	UY (Kitting)	UN, UP, UQ, UR, US, UT, UU
	80	80	SPMWH3326FP5GBT0S0	T0 (Whole Bin)	TN, TP, TQ, TR, TS, TT, TU				
4000			SPMWH3326FP5GBT3S0	T3 (MacAdam 3-step)	TU				
		SPMWH3326FP5GBTYS0	TY (Kitting)	TN, TP, TQ, TR, TS, TT, TU					
		SPMWH3326FP5GBR0S0	R0 (Whole Bin)	RN, RP, RQ, RR, RS, RT, RU					
5000	80	SPMWH3326FP5GBR3S0	R3 (MacAdam 3-step)	RU					
		SPMWH3326FP5GBRYS0	RY (Kitting)	RN, RP, RQ, RR, RS, RT, RU					
		SPMWH3326FP5GBQ0S0	Q0 (Whole Bin)	QN, QP, QQ, QR, QS, QT, QU					
5700	80	SPMWH3326FP5GBQ3S0	Q3 (MacAdam 3-step)	QU					
		SPMWH3326FP5GBQYS0	QY (Kitting)	QN, QP, QQ, QR, QS, QT, QU					
		SPMWH3326FP5GBP0S0	P0 (Whole Bin)	PN, PP, PQ, PR, PS, PT, PU					
6500	80	SPMWH3326FP5GBP3S0	P3 (MacAdam 3-step)	PU					
		SPMWH3326FP5GBPYS0	PY (Kitting)	PN, PP, PQ, PR, PS, PT, PU					

#### d) Voltage Bins ( $I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$ )

Nominal CCT	CRI	Product Code	Voltage Rank	Voltage Bin	Voltage Range
				BZ	5.8 ~ 6.0
-	_		GB	B1	6.0 ~ 6.2
-	-	-		B2	6.2 ~ 6.4
				B3	6.4 ~ 6.6



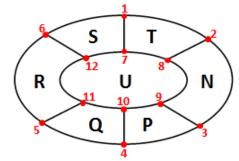
### f) Chromaticity Region & Coordinates ( $I_F = 150 \text{ mA}, T_s = 25 \text{ °C}$ )



	ССТ	Cente	er point	Major-axis	Minor-axis	Rotation
MacAdam	(K)	CIE x	CIE y	а	b	Φ
	2700	0.4578	0.4101	0.0081	0.0042	53.70
	3000	0.4338	0.4030	0.0083	0.0041	53.22
	3500	0.4073	0.3917	0.0093	0.0041	54.00
3 step	4000	0.3818	0.3797	0.0094	0.0040	53.72
	5000	0.3447	0.3553	0.0082	0.0035	59.62
	5700	0.3287	0.3417	0.0075	0.0032	59.10
	6500	0.3123	0.3282	0.0067	0.0029	58.57
	2700	0.4578	0.4101	0.0135	0.0070	53.70
	3000	0.4338	0.4030	0.0138	0.0068	53.22
	3500	0.4073	0.3917	0.0155	0.0068	54.00
5 step	4000	0.3818	0.3797	0.0157	0.0067	53.72
	5000	0.3447	0.3553	0.0137	0.0058	59.62
	5700	0.3287	0.3417	0.0125	0.0053	59.10
	6500	0.3123	0.3282	0.0112	0.0048	58.57

Note: Samsung maintains measurement tolerance of:  $Cx, Cy = \pm 0.005$ 

#### **Chromaticity Region & Coordinates** e)



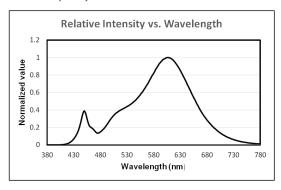
Dester	270	00K	300	3000K		00K	4000K	
Region	CIE x	CIE y						
1	0.4521	0.4142	0.4283	0.4071	0.4018	0.3957	0.3764	0.3837
2	0.4619	0.4216	0.4382	0.4146	0.4125	0.4046	0.3871	0.3926
3	0.4675	0.4175	0.4437	0.4105	0.418	0.4005	0.3925	0.3887
4	0.4634	0.4059	0.4393	0.3989	0.4128	0.3877	0.3872	0.3758
5	0.4537	0.3986	0.4293	0.3913	0.4022	0.3788	0.3765	0.3668
6	0.4481	0.4028	0.4239	0.3954	0.3966	0.3828	0.3711	0.3707
7	0.4544	0.4126	0.4305	0.4054	0.404	0.3941	0.3786	0.3821
8	0.4603	0.417	0.4364	0.41	0.4104	0.3994	0.385	0.3874
9	0.4636	0.4145	0.4397	0.4075	0.4137	0.397	0.3882	0.3851
10	0.4612	0.4076	0.4371	0.4005	0.4106	0.3893	0.385	0.3773
11	0.4553	0.4032	0.4311	0.396	0.4042	0.384	0.3786	0.372
12	0.452	0.4057	0.4279	0.3984	0.4009	0.3864	0.3754	0.3743

Decien	500	ок	57(	00K	6500K		
Region	CIE x	CIE y	CIE x	CIE y	CIE x	CIE y	
1	0.3397	0.3583	0.3242	0.3445	0.3082	0.3307	
2	0.3482	0.367	0.332	0.3524	0.3153	0.3377	
3	0.3532	0.364	0.3365	0.3496	0.3194	0.3352	
4	0.3497	0.3524	0.3333	0.339	0.3164	0.3257	
5	0.3412	0.3436	0.3254	0.331	0.3093	0.3187	
6	0.3362	0.3465	0.3209	0.3338	0.3052	0.3212	
7	0.3417	0.3571	0.326	0.3434	0.3098	0.3297	
8	0.3468	0.3623	0.3307	0.3481	0.3141	0.3339	
9	0.3498	0.3605	0.3334	0.3464	0.3166	0.3324	
10	0.3477	0.3535	0.3314	0.3401	0.3148	0.3267	
11	0.3426	0.3483	0.3267	0.3353	0.3105	0.3225	
12	0.3396	0.35	0.324	0.3369	0.308	0.324	

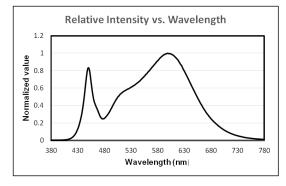
#### 3. Typical Characteristics Graphs

#### a) Spectrum Distribution (I<sub>F</sub> = 150 mA, T<sub>s</sub> = 25 °C)

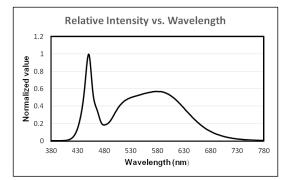
CCT : 2700K (80 CRI)



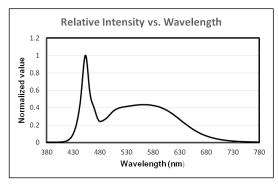
CCT : 3500K (80 CRI)



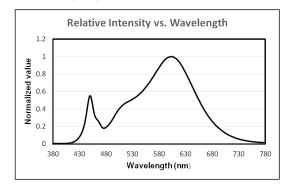
CCT : 5000K (80 CRI)



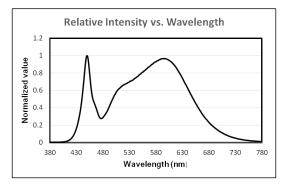
CCT : 6500K (80 CRI)



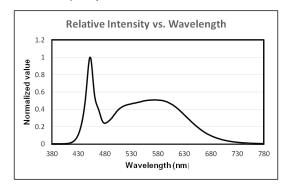
CCT : 3000K (80 CRI)



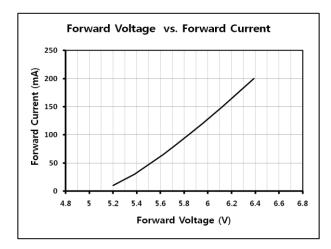
CCT : 4000K (80 CRI)



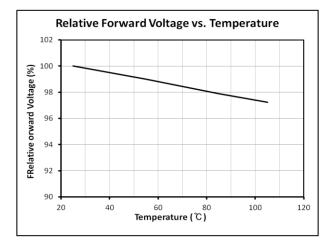




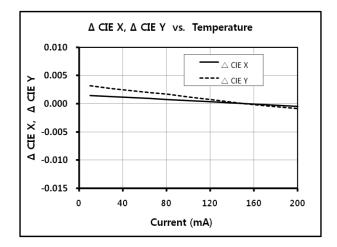
#### b) Forward Current Characteristics (T<sub>s</sub> = 25 °C)

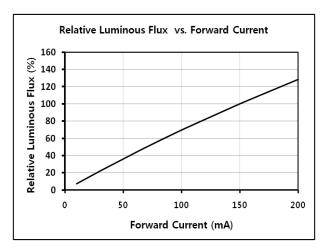


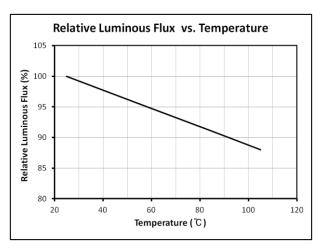
#### c) Temperature Characteristics (I<sub>F</sub> = 150 mA)

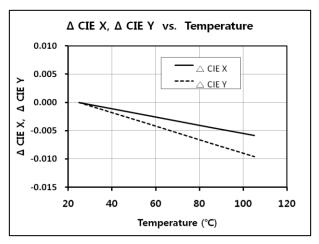


#### c) Color Shift Characteristics (Ta=25°C, IF=150mA)

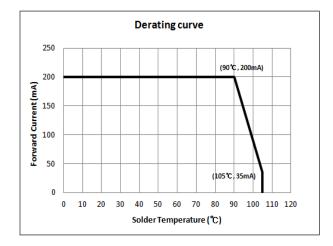




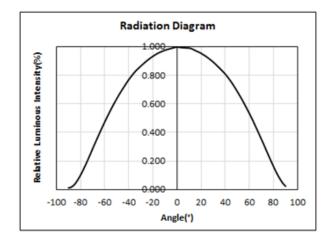




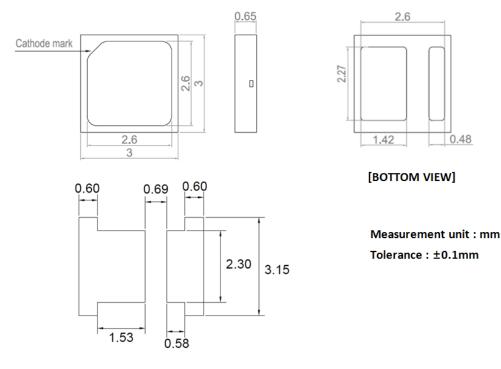
### e) Derating curve



# f) Beam angle Characteristics



#### 4. Outline Drawing & Dimension





#### Notes:

- 1) This LED has built-in ESD protection device(s) connected in parallel to LED chip(s).
- 2)  $T_s$  point and measurement method:
  - (1) Measure one point at the cathode pad, if necessary remove PSR of PCB to reach Ts point.
  - (2) All pads must be soldered to the PCB to dissipate heat properly, otherwise the LED can be damaged.

#### Precautions:

- Pressure on the LEDs will influence to the reliability of the LEDs. Precautions should be taken to avoid strong pressure on the LEDs. Do not put stress on the LEDs during heating.
- Re-soldering should not be done after the LEDs have been soldered. If re-soldering is unavoidable, LED's characteristics should be carefully checked before and after such repair.
- 3) Do not stack assembled PCBs together. Since materials of LEDs is soft, abrasion between two PCB assembled with LED might cause catastrophic failure of the LEDs.

# 5. Reliability Test Items & Conditions

#### a) Test Items

Test Item	Test Condition	Test Hour / Cycle	Sample No.
Room Temperature Life Test	25 °C, DC 150 mA	1000 h	22
High Temperature Life Test	85 °C, DC 150 mA	1000 h	22
High Temperature Humidity Life Test	60 °C, 90 % RH, DC 150 mA	1000 h	22
Low Temperature Life Test	-40 °C, DC 150 mA	1000 h	22
Powered Temperature Cycle Test	-45 °C / 20 min ↔ 85 °C / 20 min, sweep 100 min cycle on/off: each 5 min, DC 150 mA	100 cycles	22
Thermal Cycle	-40 °C / 15 min ↔ 100 °C / 15 min → Hot plate 180 °C	500 cycles	100
High Temperature Storage	100 °C	1000 h	11
Low Temperature Storage	-40 °C	1000 h	11
ESD (HBM)	R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 1.5 kΩ C: 100 pF	5 times	30
ESD (MM)	R <sub>1</sub> : 10 MΩ R <sub>2</sub> : 0 C: 200 pF	5 times	30
Vibration Test	20~2000~20 Hz, 200 m/s², sweep 4 min X, Y, Z 3 direction, each 1 cycle	4 cycles	11
Mechanical Shock Test	1500 g, 0.5 ms 3 shocks each X-Y-Z axis	5 cycles	11

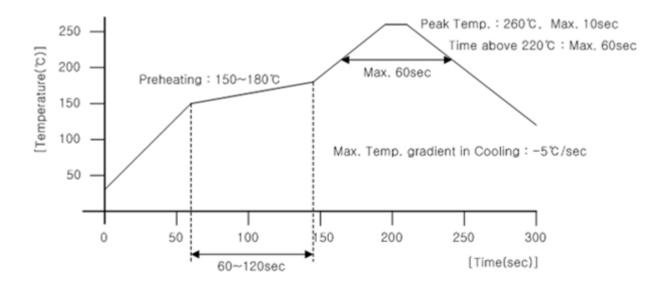
### b) Criteria for Judging the Damage

Item	Symbol	Test Condition	Limit	
	Cymbol	(T <sub>s</sub> = 25 °C)	Min	Max
Forward Voltage	VF	I <sub>F</sub> = 150 mA	Init. Value * 0.9	Init. Value * 1.1
Luminous Flux	Φ <sub>v</sub>	I <sub>F</sub> = 150 mA	Init. Value * 0.7	Init. Value * 1.1

### 6. Soldering Conditions

#### a) Reflow Conditions (Pb free)

Reflow frequency: 2 times max.

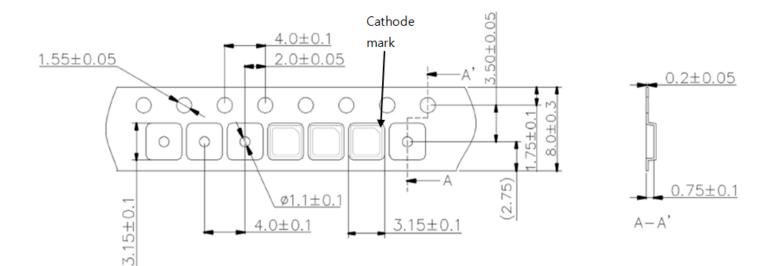


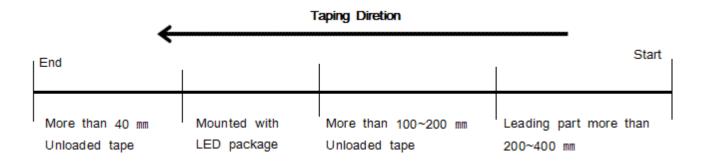
#### b) Manual Soldering Conditions

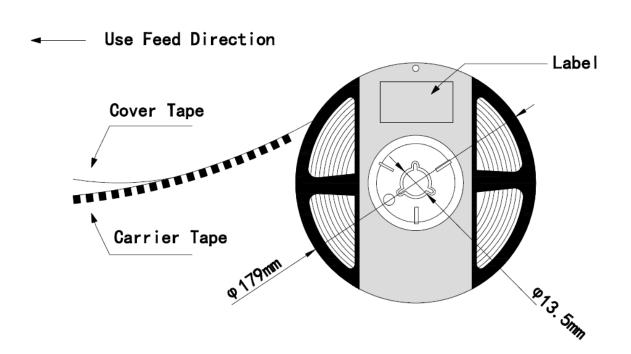
Not more than 5 seconds @ max. 300 °C, under soldering iron.

#### a) Taping Dimension

(unit: mm)







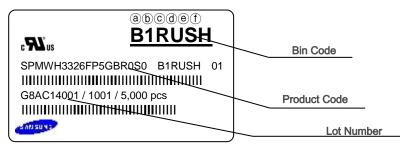
#### Notes:

- 1) Quantity: The quantity/reel is 5,000 pcs
- 2) Cumulative Tolerance: Cumulative tolerance / 10 pitches is ±0.2 mm
- Adhesion Strength of Cover Tape: Adhesion strength is 0.1-0.7 N when the cover tape is turned off from the carrier tape at 10° angle to the carrier tape
- 4) Packaging: P/N, Manufacturing data code no. and quantity are indicated on the aluminum packing bag

(unit: mm)

#### 8. Label Structure

#### a) Label Structure



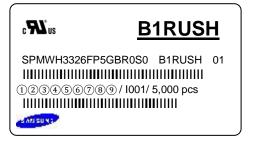
Note: Denoted bin code and product code above is only an example (see description on page 4)

Bin Code:

- (a) (b): Forward Voltage bin (refer to page 7)
- ©d: Chromaticity bin (refer to page 8-10)
- (e) f): Luminous Flux bin (refer to page 5)

#### b) Lot Number

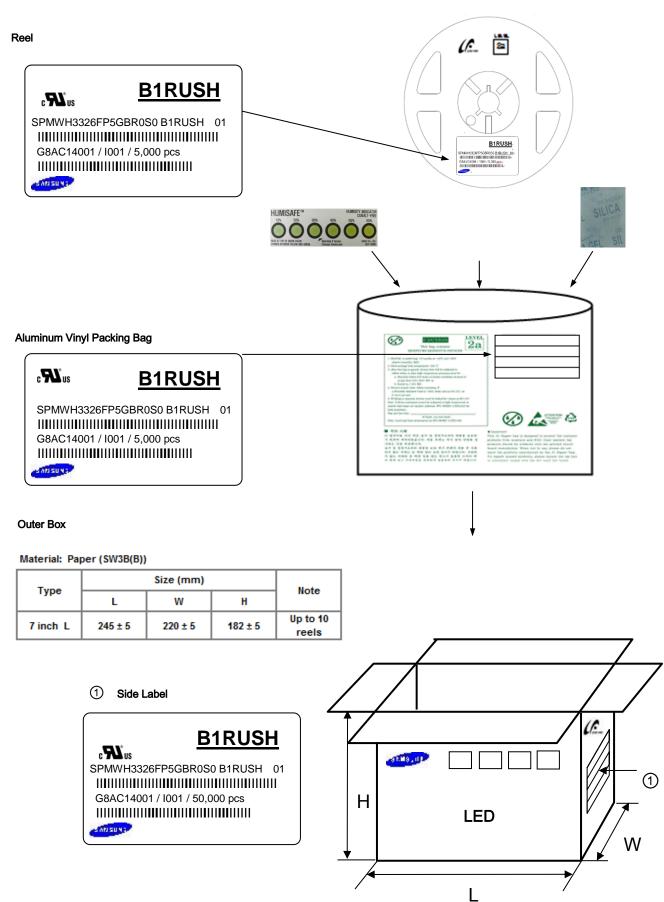
The lot number is composed of the following characters:



- (1)(2) : Production site (G8 : China Xiamen)
- ③ : Product state (A: Normal, B: Bulk, C: First Production, R: Reproduction, S: Sample)
- ④ : Year (C: 2018, D: 2019, E: 2020...)
- (5) : Month (1~9, A, B, C)
- 6 : Day (1~9, A, B~V)
- (7)(8)(9) : Product serial number (001 ~ 999)

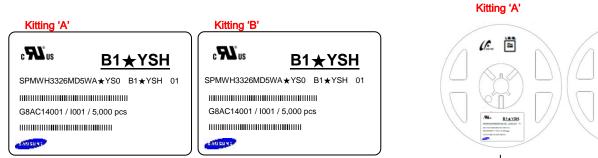
#### 9. Packing Structure

#### a) Packing Process (The quantity of PKG on the Reel to be Max 5,000pcs)

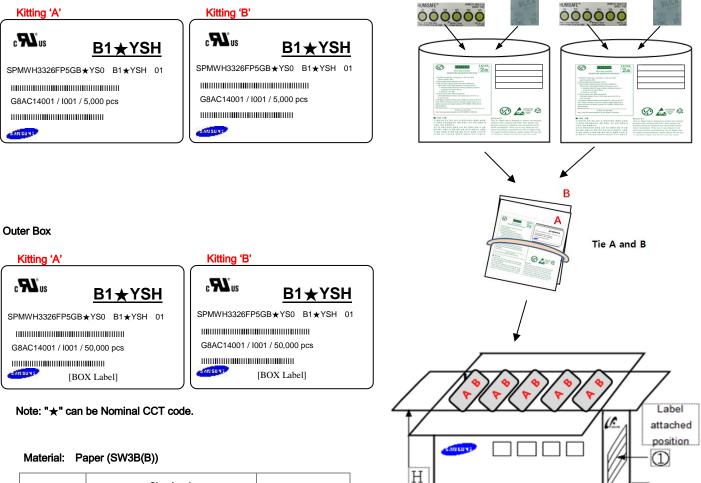


Packing Process for kitting (The quantity of PKG on the Reel to be Max 5,000pcs) b)

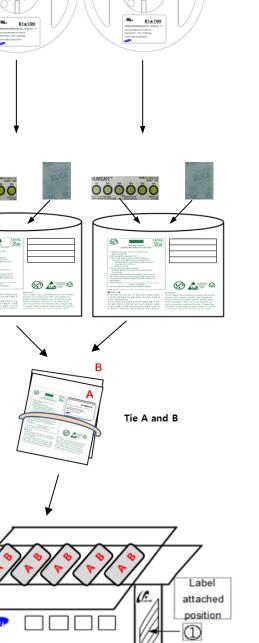
#### Reel



#### Aluminum Vinyl Packing Bag



Туре	Size (mm)			Note
туре	L	w	н	NOLO
7 inch L	245 ± 5	220 ± 5	182 ± 5	Up to 10 reels

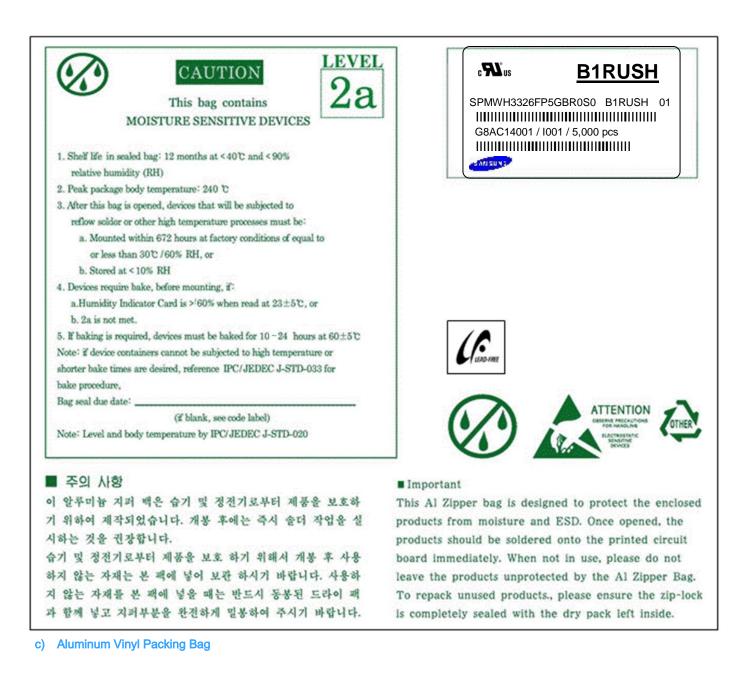


CHIP LED

L

Kitting 'B'

( E



#### c) Silica Gel & Humidity Indicator Card inside Aluminum Vinyl Bag



#### READ AT LAVENDER BETWEEN PINK & BLUE CLARIANT CIARIANT CIARIANT

#### 10. Precautions in Handling & Use

- 1) For over-current-proof function, customers are recommended to apply resistors to prevent sudden change of the current caused by slight shift of the voltage.
- 2) This device should not be used in any type of fluid such as water, oil, organic solvent, etc. When washing is required, IPA is recommended to use.
- 3) When the LEDs illuminate, operating current should be decided after considering the ambient maximum temperature.
- 4) LEDs must be stored in a clean environment. If the LEDs are to be stored for three months or more after being shipped from Samsung, they should be packed by a sealed container with nitrogen gas injected (shelf life of sealed bags: 12 months, temperature ~40 °C, ~90 % RH).
- After storage bag is opened, device subjected to soldering, solder reflow, or other high temperature processes must be:
  a. Mounted within 672 hours (28 days) at an assembly line with a condition of no more than 30 °C / 60 % RH, or
  b. Stored at <10 % RH</li>
- 6) Repack unused products with anti-moisture packing, fold to close any opening and then store in a dry place.
- 7) Devices require baking before mounting, if humidity card reading is >60 % at 23 ± 5 °C.
- 8) Devices must be baked for 10~24 hours at 60 ± 5 °C, if baking is required.
- 9) The LEDs are sensitive to the static electricity and surge. It is recommended to use a wrist band or anti-electrostatic glove when handling the LEDs. If voltage exceeding the absolute maximum rating is applied to LEDs, it may cause damage or even destruction to LED devices. Damaged LEDs may show some unusual characteristics such as increase in leak current, lowered turn-on voltage, or abnormal lighting of LEDs at low current.
- 10) VOCs (Volatile Organic Compounds) can be generated from adhesives, flux, hardener or organic additives used in luminaires (fixtures). Transparent LED silicone encapsulant is permeable to those chemicals and they may lead a discoloration of encapsulant when they exposed to heat or light. This phenomenon can cause a significant loss of light emitted (output) from the luminaires (fixtures). In order to prevent these problems, we recommend users to know the physical properties of the materials used in luminaires, and they must be selected carefully.
- 11) Risk of sulfurization (or tarnishing)

The LED from Samsung Electronics Co., Ltd. uses a silver-plated lead frame and its surface color may change to black (or dark colored) when it is exposed to sulfur (S), chlorine (Cl) or other halogen compound. Sulfurization of lead frame may cause intensity degradation, change of chromaticity coordinates and, in extreme cases, open circuit. It requires caution. Due to possible sulfurization of lead frame, LED should not be used and stored together with oxidizing substances made of materials such as: rubber, plain paper, lead solder cream, etc.

# Legal and additional information.

#### About Samsung Electronics Co., Ltd.

Samsung Electronics Co., Ltd. inspires the world and shapes the future with transformative ideas and technologies that redefine the worlds of TVs, smartphones, wearable devices, tablets, cameras, digital appliances, printers, medical equipment, network systems, and semiconductor and LED solutions. We are also leading in the Internet of Things space with the open platform SmartThings, our broad range of smart devices, and through proactive cross-industry collaboration. We employ 319,000 people across 84 countries with annual sales of US \$196 billion. To discover more, and for the latest news, feature articles and press material, please visit the Samsung Newsroom at news.samsung.com.

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